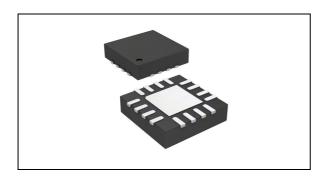
### STSPIN250



### Low voltage brush DC motor driver

Datasheet - production data



#### **Features**

- Operating voltage from 1.8 to 10 V
- Maximum output current 2.6 A<sub>rms</sub> with OUTAx paralled to OUTBx
- $R_{DS(ON)}$  HS + LS = 0.2  $\Omega$  typ.
- · Current control with programmable off-time
- Full protection set
  - Non-dissipative overcurrent protection
  - Short-circuit protection
  - Thermal shutdown
- Energy saving and long battery life with standby consumption less than 80 nA

### **Applications**

Battery-powered DC motor applications such as:

- Toys
- Portable printers
- Robotics
- · Point of sales (POS) devices
- Portable medical equipment
- Healthcare and wellness devices (shavers and toothbrushes)

#### **Description**

The STSPIN250 is a single brush DC motor driver integrating a low  $R_{ds(ON)}$  power stage in a small VFQFPN 3 x 3 mm package.

The full-bridge implements a PWM current controller with fixed OFF time.

The device is designed to operate in batterypowered scenarios and can be forced in a zeroconsumption state allowing a significant increase in battery life.

The device offers a complete set of protection features including overcurrent, overtemperature and short-circuit protection.

Contents STSPIN250

# **Contents**

1	Bloc	ck diagram	5
2	Elec	trical data	6
	2.1	Absolute maximum ratings	6
	2.2	Recommended operating conditions	6
	2.3	Thermal data	7
	2.4	ESD protections	7
3	Elec	trical characteristics	8
4	Pin o	description	10
5	Турі	cal applications	12
6	Devi	ice description	13
	6.1	Standby and power-up	13
	6.2	Motor driving	13
	6.3	PWM current control	15
		TOFF adjustment	17
	6.4	Overcurrent and short-circuit protections	18
	6.5	Thermal shutdown	20
7	Grap	ohs	21
8	Pack	kage information	23
	8.1	VFQFPN 3 x 3 x 1.0- 16L package information	23
9	Orde	ering information	25
10	Revi	ision history	25



STSPIN250 List of tables

# List of tables

Table 1.	Absolute maximum ratings	6
Table 2.	Recommended operating conditions	6
Table 3.	Thermal data	7
Table 4.	ESD protection ratings	7
Table 5.	Electrical characteristics	
Table 6.	Pin description	. 10
Table 7.	Typical application values	
Table 8.	Truth table	. 13
Table 9.	ON and slow decay states	. 15
Table 10.	Recommended R <sub>RCOFF</sub> and C <sub>RCOFF</sub> values according to R <sub>OFF</sub>	. 17
Table 11.	VFQFPN 3 x 3 x 1.0 - 16L package mechanical data	. 24
Table 12.	Device summary	. 25
Table 13.	Document revision history	. 25



List of figures STSPIN250

# List of figures

Figure 1.	Block diagram	5
Figure 2.	Pin connection (top view)	. 10
Figure 3.	Typical application schematic	. 12
Figure 4.	Timing diagram	. 14
Figure 5.	PWM current control	. 16
Figure 6.	OFF time regulation circuit	. 17
Figure 7.	OFF time vs R <sub>OFF</sub> value	. 17
Figure 8.	Overcurrent and short-circuit protections management	
Figure 9.	Disable time versus R <sub>EN</sub> and C <sub>EN</sub> values (V <sub>DD</sub> = 3.3 V)	. 19
Figure 10.	Disable time versus $R_{EN}$ and $C_{EN}$ values ( $V_{DD}$ = 1.8 V)	. 19
Figure 11.	Thermal shutdown management	. 20
Figure 12.	Power stage resistance versus supply voltage	. 21
Figure 13.	Power stage resistance versus temperature	. 21
Figure 14.	Overcurrent threshold versus supply voltage	. 22
Figure 15.	VFQFPN 3 x 3 x 1.0 - 16L package outline	. 23
Figure 16	VEOEPN 3 x 3 x 1.0 - 16L recommended footprint	24



STSPIN250 Block diagram

# 1 Block diagram

Figure 1. Block diagram STBY\RESET \$ OUTA1 REF EN\FAULT Brush DC OUTA2 SENSEA Control logic РΗ OUTB1 PWM OUTB2 TOFF Oscillator SENSEB TEST0 TEST1 GND

AM039993V1

Electrical data STSPIN250

### 2 Electrical data

## 2.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Test condition	Value	Unit
V <sub>S</sub>	Supply voltage	-	-0.3 to 11	V
V <sub>IN</sub>	Logic input voltage	-	-0.3 to 5.5	V
V <sub>OUT</sub> - V <sub>SENSE</sub>	Output to sense voltage drop	-	up to 12	V
V <sub>S</sub> - V <sub>OUT</sub>	Supply to output voltage drop	-	up to 12	V
$V_{SENSE}$	Sense pins voltage	-	-1 to 1	V
$V_{REF}$	Reference voltage input	-	-0.3 to 1	V
I <sub>OUT,RMS</sub>	Continuous power stage output current (OUTAx // OUTBx)	-	2.6	Arms
T <sub>j,OP</sub>	Operative junction temperature40 to 150			°C
T <sub>j,STG</sub>	Storage junction temperature	-	-55 to 150	°C

## 2.2 Recommended operating conditions

Table 2. Recommended operating conditions

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V <sub>S</sub>	Supply voltage	-	1.8	-	10	V
V <sub>IN</sub>	Logic input voltage	-	0	-	5	V
V <sub>REF</sub>	Reference voltage input	-	0.1	-	0.5	V
t <sub>INw</sub>	Logic input positive/negative pulse width	-	300	-	-	ns

STSPIN250 Electrical data

### 2.3 Thermal data

Table 3. Thermal data

Symbol	Parameter	Conditions		Unit
R <sub>thJA</sub>	Junction to ambient thermal resistance	Natural convection, according to JESD51-2A <sup>(1)</sup>	57.1	°C/W
R <sub>thJCtop</sub>	Junction to case thermal resistance (top side)	Simulation with cold plate on package top	67.3	°C/W
R <sub>thJCbot</sub>	Junction to case thermal resistance (bottom side)	Simulation with cold plate on exposed pad	9.1	°C/W
R <sub>thJB</sub>	Junction to board thermal resistance	According to JESD51-8 <sup>(1)</sup>	23.3	°C/W
$\Psi_{JT}$	Junction to top characterization According to JESD51-2A <sup>(1)</sup>		3.3	°C/W
ΨЈВ	Junction to board characterization	According to JESD51-2A <sup>(1)</sup>	22.6	°C/W

<sup>1.</sup> Simulated on a 21.2 x 21.2 mm board, 2s2p 1 Oz copper and four 300  $\mu m$  via below exposed pad.

## 2.4 ESD protections

Table 4. ESD protection ratings

Symbol	Parameter	Test condition	Class	Value	Unit
HBM	Human body model	Conforming to ANSI/ESDA/JEDEC JS-001-2014	H2	2	kV
CDM	Charge device model	Conforming to ANSI/ESDA/JEDEC JS-001-2014	C2a	500	V

Electrical characteristics STSPIN250

## 3 Electrical characteristics

Testing conditions:  $V_S$  = 5 V,  $T_j$  = 25 °C, unless otherwise specified.

**Table 5. Electrical characteristics** 

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Supply						
V <sub>Sth(ON)</sub>	V <sub>S</sub> turn-on voltage	V <sub>S</sub> rising from 0 V	1.45	1.65	1.79	V
V <sub>Sth(OFF)</sub>	V <sub>S</sub> turn-off voltage	V <sub>S</sub> falling from 5 V	1.3	1.45	1.65	V
V <sub>Sth(HYS)</sub>	V <sub>S</sub> hysteresis voltage	-	-	180		mV
1-	V- supply current	No commutations EN = 0 $R_{OFF} = 160 \text{ k}\Omega$	-	960	1300	μА
l <sub>S</sub>	V <sub>S</sub> supply current	No commutations EN = 1 $R_{OFF}$ = 160 kΩ	-	1500	1950	μА
I <sub>S,STBY</sub>	V <sub>S</sub> standby current	STBY = 0 V	-	10	80	nA
V <sub>STBYL</sub>	Standby low logic level input voltage	-	-	-	0.9	V
V <sub>STBYH</sub>	Standby logic level input voltage	-	1.48	-	-	V
Power stage						
	Total on resistance HS + LS <sup>(1)</sup> S (OUTAx // OUTBx)	V <sub>S</sub> = 10 V I <sub>OUT</sub> = 1.3 A	-	0.2	0.33	
R <sub>DS(ON)HS+LS</sub>		$V_S = 10 \text{ V}$ $I_{OUT} = 1.3 \text{ A}$ $Tj = 125 \text{ °C}^{(2)}$	-	0.27	0.44	Ω
		V <sub>S</sub> = 3 V, I <sub>OUT</sub> = 0.4 A	-	0.27	0.4	
1	Leakage current	OUTx = V <sub>S</sub>	-	-	1	μA
I <sub>DSS</sub>	Leakage current	OUTx = GND	- 1	-	i	μΛ
$V_{DF}$	Freewheeling diode forward voltage	I <sub>D</sub> = 1.3 A	-	0.9	i	V
t <sub>rise</sub>	Rise time	V <sub>S</sub> = 10 V; unloaded outputs	-	10	ı	ns
t <sub>fall</sub>	Fall time	V <sub>S</sub> = 10 V; unloaded outputs	-	10	i	ns
t <sub>DT</sub>	Dead time	-	-	50	-	ns
PWM current	controller					
Volla accord I Sensing offset		V <sub>REF</sub> = 0.5 V Internal reference 20% V <sub>REF</sub>	-15	-	+15	mV
to	Total OFF time	R <sub>OFF</sub> = 10 kΩ	-	9	ı	μs
t <sub>OFF</sub>	TOTAL OFF LITTE	R <sub>OFF</sub> = 160 kΩ	-	125	-	μs

Table 5. Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
$\Delta f_{\sf OSC}$	Oscillator precision	fosc/fosc,iD	-20%	-	+20%	-
t <sub>OFF,jitter</sub>	Total OFF time jittering	R <sub>OFF</sub> = 10 kΩ	-	-	2%	-
Logic IOs						
V <sub>IH</sub>	High logic level input voltage -		1.6	-	-	V
V <sub>IL</sub>	Low logic level input voltage	-	-	-	0.6	V
V <sub>RELEASE</sub>	FAULT open drain release voltage	-	-	-	0.4	V
V <sub>OL</sub>	Low logic level output voltage	I <sub>OL</sub> = 4 mA	-	-	0.4	V
R <sub>STBY</sub>	STBY pull-down resistance	-	-	36	-	kΩ
I <sub>PDEN</sub>	EN pull-down current	-	-	10.5	-	μΑ
t <sub>ENd</sub>	EN input propagation delay	From EN falling edge to OUT high impedance	-	55	-	ns
t <sub>PWM,d(ON)</sub>	PWM turn-on propagation delay	See Figure 4 on page 14	-	125	-	ns
t <sub>PWM,d(OFF)</sub>	PWM turn-off propagation delay	See Figure 4	-	140	-	ns
t <sub>PH,d</sub>	PH propagation delay	See Figure 4	-	125	-	ns
Protections						
T <sub>jSD</sub> Thermal shutdown threshold		-	-	160	-	°C
T <sub>jSD,Hyst</sub>	Thermal shutdown hysteresis	-	-	40	-	°C
	Oversurrent threehold	Single OUT	-	2	-	۸
loc	Overcurrent threshold	OUTAx // OUTBx	-	4	-	Α

<sup>1.</sup> Production test made on single outputs.

<sup>2.</sup> Based on characterization data on a limited number of samples, not tested during production.

Pin description STSPIN250

# 4 Pin description

 $\mathsf{STBY} \backslash$ TEST1 TEST0 EN\FAU LT RESET 16 15 14 13 PH (12 TO FF **PWM** ( 11 REF **EPAD** (10 OUTB1 OUTA1 SENSEB SENSEA 7 8 5 OUTA2 ٧S GND OUTB2 AM039994

Figure 2. Pin connection (top view)

Note:

The exposed pad, TEST0 and TEST1 pins must be connected to ground. OUTA1 and OUTB1 must be connected together. OUTA2 and OUTB2 must be connected together. SENSEA and SENSEB must be connected together.

Table 6. Pin description

No.	Name	Туре	Function
1	PH	Logic input	Phase input
2	PWM	Logic input	PWM input
3	OUTA1	Power output	Power bridge output side A1, must be connected to OUTB1.
4	SENSEA	Power output	Sense output A, must be connected to SENSEB.
5	OUTA2	Power output Power bridge output side A2, must be connected OUTB2.	
6	VS	Supply	Device supply voltage.
7, EPAD	GND	Ground	Device ground.
8	OUTB2	Power output	Power bridge output side B2, must be connected to OUTA2.
9	SENSEB	Power output	Sense output B, must be connected to SENSEA.

STSPIN250 Pin description

Table 6. Pin description (continued)

No.	o. Name Type Function		Function
10	OUTB1	Power output	Power bridge output side B1, must be connected to OUTA1.
11	REF	Analog input	Reference voltage for the current limiter circuitry.
12	12 TOFF Analog input		Internal oscillator frequency adjustment.
13	13 EN\FAULT Logic input\ open drain output		Logic input 5 V compliant whit and open drain output.  This is the power stage enable (when low the power stage is turned off) and it is forced low through the integrated open-drain MOSFET when a failure occurs.
14	14 STBY\RESET Logic input		Logic input 5 V compliant.  When forced low the device is forced into the low consumption mode.
15	15 TEST0 -		Reserved pin. This pin must be connected to ground.
16	TEST1	-	Reserved pin. This pin must be connected to ground.

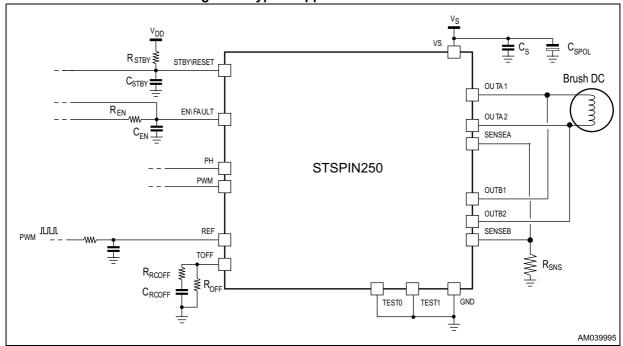
Typical applications STSPIN250

# 5 Typical applications

Table 7. Typical application values

Name	Value
C <sub>S</sub>	2.2 μF / 16 V
C <sub>SPOL</sub>	22 μF / 16 V
R <sub>SNS</sub>	330 mΩ / 1 W
C <sub>EN</sub>	10 nF / 6.3 V
R <sub>EN</sub>	18 kΩ
C <sub>STBY</sub>	1 nF / 6.3 V
R <sub>STBY</sub>	18 kΩ
C <sub>RCOFF</sub>	22 nF
R <sub>RCOFF</sub>	1 kΩ
R <sub>OFF</sub>	47 kΩ (t <sub>OFF</sub> $\cong$ 37 μs)

Figure 3. Typical application schematic



STSPIN250 Device description

## 6 Device description

The STSPIN250 is a single brush DC motor driver integrating a PWM current controller and a power stage composed by a fully-protected full-bridge.

#### 6.1 Standby and power-up

The device provides a low settable consumption mode forcing the STBY\RESET input below the  $V_{STBYL}$  threshold.

When the device is in the standby status, the power stage is disabled (outputs are in high impedance) and the supply to the integrated control circuitry is cut-off.

#### 6.2 Motor driving

The outputs of the full-bridge are controlled by the PWM and PH inputs as listed in Table 8.

**EN\FAULT** РΗ **PWM** OUTx1 OUT<sub>x2</sub> **Full-bridge condition** 0 Х Х HiZ HiZ Disabled 0 0 **GND GND** Both LS on 1 0 VS 1 1 **GND** HSx2 and LSx1 on (current X1  $\leftarrow$  X2) 1 1 0 **GND GND** Both LS on VS 1 1 1 **GND** HSx1 and LSx2 on (current X1  $\rightarrow$  X2)

Table 8. Truth table

STSPIN250 **Device description** 

РΗ PWM t<sub>PWM,d(ON)</sub>  $t_{PWM,d(OFF)}$ 90% t<sub>PH,d</sub> OUTx1 10% 10% OUTx2 10% AM039996

Figure 4. Timing diagram

STSPIN250 Device description

#### 6.3 PWM current control

The device implements a current controller.

The voltage on the sense pins ( $V_{SENSE}$ ) is compared to the reference voltage applied on the REF pin ( $V_{REF}$ ).

When  $V_{SENSE} > V_{REF}$ , the current limiter is triggered, the OFF time counter is started, and the decay sequence is performed.

The decay sequence starts turning on all the low sides of the full-bridge. After the programmed OFF time the system returns to the ON state.

PH	PWM	ON	Decay
0	0	HSx1 = OFF <b>LSx1 = ON</b> HSx2 = OFF <b>LSx2 = ON</b>	N.A. <sup>(1)</sup>
0	1	HSx1 = OFF LSx1 = ON HSx2 = ON LSx2 = OFF	HSx1 = OFF <b>LSx1 = ON</b> HSx2 = OFF <b>LSx2 = ON</b>
1	0	HSx1 = OFF <b>LSx1 = ON</b> HSx2 = OFF <b>LSx2 = ON</b>	N.A. <sup>(1)</sup>
1	1	HSx1 = ON LSx1 = OFF HSx2 = OFF LSx2 = ON	HSx1 = OFF <b>LSx1 = ON</b> HSx2 = OFF <b>LSx2 = ON</b>

Table 9. ON and slow decay states

The reference voltage value, V<sub>REF</sub>, has to be selected according to the load current target value (peak value) and sense resistors value.

#### **Equation 1**

In choosing the sense resistors value, two main issues must be taken into account:

- The sensing resistor dissipates energy and provides dangerous negative voltages on the SENSE pins during the current recirculation. For this reason the resistance of this component should be kept low (using multiple resistors in parallel will help obtaining the required power rating with standard resistors).
- The lower is the R<sub>SNSx</sub> value, the higher is the peak current error due to noise on the V<sub>REF</sub> pin and to the input offset of the current sense comparator: too low values of R<sub>SNSx</sub> must be avoided.

<sup>1.</sup> During decays the input values are ignored until the system returns to ON condition (decay time expired).

Device description STSPIN250

Figure 5. PWM current control

STSPIN250 Device description

#### **TOFF adjustment**

The decay time is adjusted through an external resistor connected between the TOFF pin and ground as shown in *Figure 6*. A small RC series must be inserted in parallel with the regulator resistor in order to increase the stability of the regulation circuit according indications listed in *Table 10*.

TOFF

RRCOFF

ROFF

ROFF

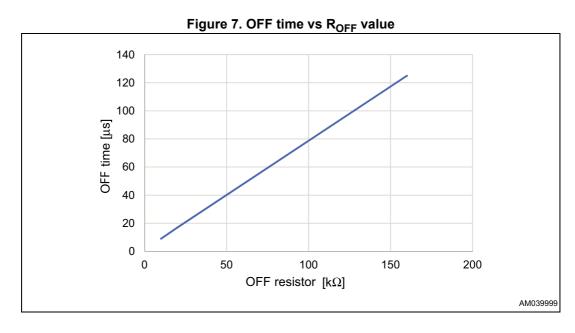
AM039998

Figure 6. OFF time regulation circuit

The relation between the OFF time and the external resistor value is shown in the graph of *Figure 7*. The value typically ranges from 10  $\mu$ s to 150  $\mu$ s.

Table 10. Recommended  $\rm R_{RCOFF}$  and  $\rm C_{RCOFF}$  values according to  $\rm R_{OFF}$ 

ROFF	RRCOFF	CRCOFF
10 kΩ ≤ R <sub>OFF</sub> < 82 kΩ	1 kΩ	22 nF
82 kΩ $\leq$ R <sub>OFF</sub> $\leq$ 160 kΩ	2.2 kΩ	22 nF



Device description STSPIN250

#### 6.4 Overcurrent and short-circuit protections

The device embeds circuitry protecting each power output against the overload and short-circuit conditions (short-circuit to ground, short-circuit to VS and short-circuit between outputs).

When the overcurrent or the short-circuit protection is triggered, the power stage is disabled and the EN\FAULT input is forced low through the integrated open-drain MOSFET discharging the external  $C_{\text{FN}}$  capacitor.

The power stage is kept disabled and the open-drain MOSFET is kept ON until the EN\FAULT input falls below the  $V_{RELEASE}$  threshold, then the  $C_{EN}$  capacitor is charged through the  $R_{EN}$  resistor.

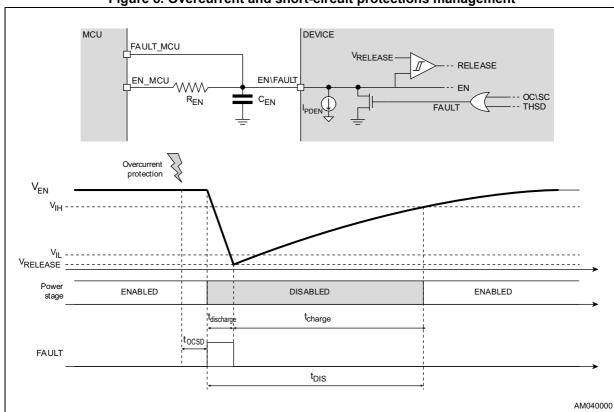


Figure 8. Overcurrent and short-circuit protections management

The total disable time after an overcurrent event can be set by properly sizing the external network connected to the EN\FAULT pin (refer to *Figure 9* and *Figure 10*):

#### **Equation 2**

$$t_{DIS} = t_{discharge} + t_{charge}$$

But  $t_{\text{charge}}$  is normally very higher than  $t_{\text{discharge}}$  we can consider only the second one contribution:

$$t_{\text{DIS}} \cong R_{\text{EN}} \cdot C_{\text{EN}} \cdot ln \frac{(V_{\text{DD}} - R_{\text{EN}} \cdot I_{\text{PD}}) - V_{\text{RELEASE}}}{(V_{\text{DD}} - R_{\text{EN}} \cdot I_{\text{PD}}) - V_{\text{IH}}}$$

Where  $V_{DD}$  is the pull-up voltage of the  $R_{EN}$  resistor.

577

STSPIN250 **Device description** 

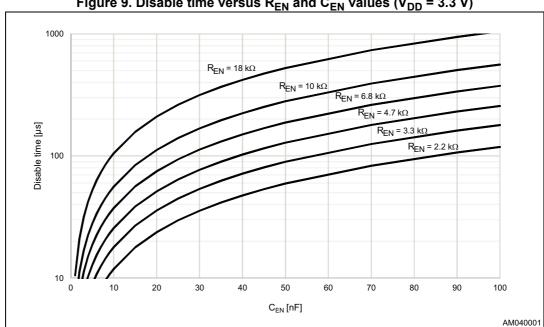
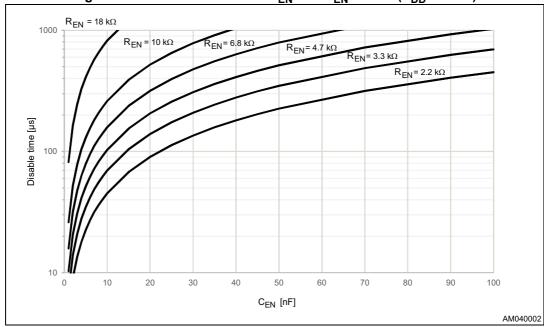


Figure 9. Disable time versus  $R_{EN}$  and  $C_{EN}$  values ( $V_{DD}$  = 3.3 V)





Device description STSPIN250

#### 6.5 Thermal shutdown

The device embeds circuitry protecting it from the overtemperature condition.

When the thermal shutdown temperature is reached the power stage is disabled and the EN\FAULT input is forced low through the integrated open-drain MOSFET.

The protection and the EN\FAULT output are released when the IC temperature returns below a safe operating value ( $T_{jSD}$  -  $T_{jSD,Hyst}$ ).

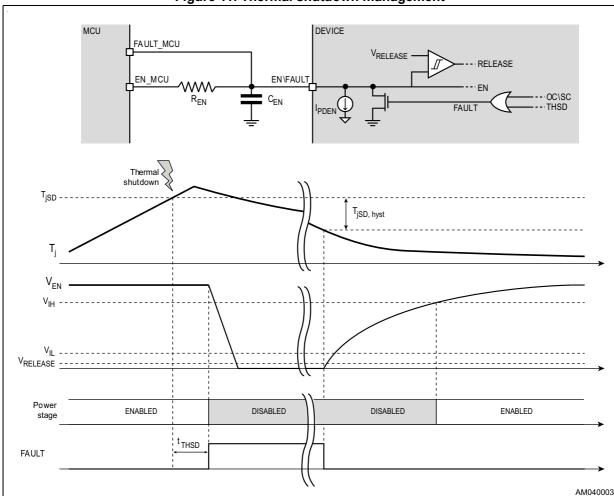


Figure 11. Thermal shutdown management

STSPIN250 **Graphs** 

#### 7 **Graphs**

Figure 12. Power stage resistance versus supply voltage

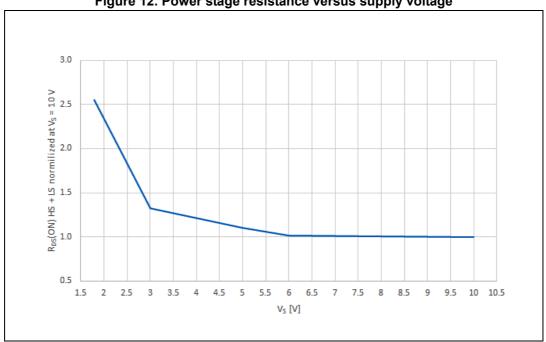
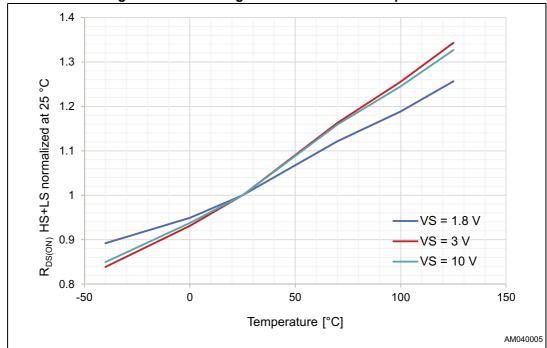


Figure 13. Power stage resistance versus temperature



Graphs STSPIN250

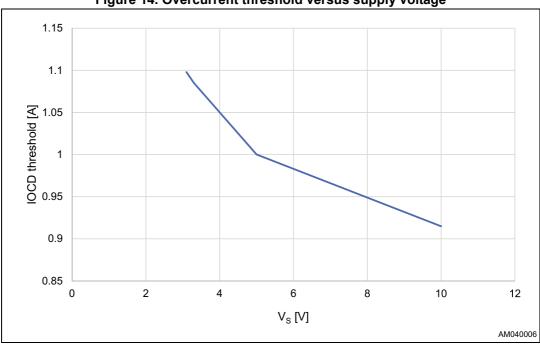


Figure 14. Overcurrent threshold versus supply voltage

STSPIN250 Package information

## 8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

## 8.1 VFQFPN 3 x 3 x 1.0- 16L package information

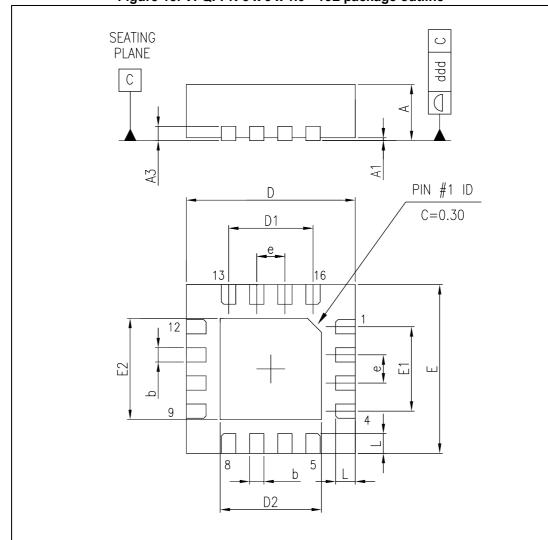


Figure 15. VFQFPN 3 x 3 x 1.0 - 16L package outline

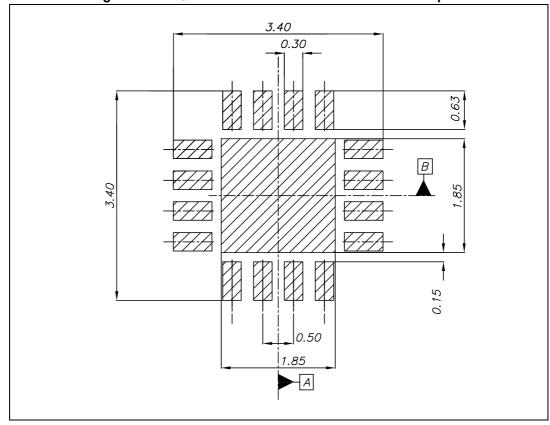
Package information STSPIN250

Table 11. VFQFPN 3 x 3 x 1.0 - 16L package mechanical data<sup>(1)</sup>

Symbol	Dimensions (mm)		
	Min.	Тур.	Max.
А	0.80	0.90	1.00
A1	-	0.02	-
A3	-	0.20	-
b	0.18	0.25	0.30
D	2.85	3.00	3.15
D2	1.70	1.80	1.90
E	2.85	3.00	3.15
E2	1.70	1.80	1.90
е	-	0.50	-
L	0.45	0.50	0.55

VFQFPN stands for "Thermally Enhanced Very thin Fine pitch Quad Packages No lead". Very thin: 0.80 < A ≤ 1.00 mm / fine pitch: e < 1.00 mm. The pin #1 identifier must exist on the top surface of the package by using indentation mark or other feature of the package body.

Figure 16. VFQFPN 3 x 3 x 1.0 - 16L recommended footprint



# 9 Ordering information

**Table 12. Device summary** 

Order code	Package	Packaging
STSPIN250	VFQFPN 3 x 3 x1.0 - 16L	Tape and reel

# 10 Revision history

**Table 13. Document revision history** 

Date	Revision	Changes
17-Oct-2016	1	Initial release.
04-Nov-2016	2	Updated document status to: Datasheet - production data on page 1.  Updated Figure 1 on page 5 and Figure 12 on page 21 (replaced by new figures).  Updated Table 2 on page 6 (added new parameter t <sub>INw</sub> ).  Minor modifications throughout document.

#### **IMPORTANT NOTICE - PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2016 STMicroelectronics - All rights reserved